NSN 5961-00-159-6583

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-159-6583 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.065 inches and 0.075 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, peak **Current Rating Per Characteristic:** 20.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 125.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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